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November 2013

FQPF16N15

N-Channel QFET[®] MOSFET 150 V, 11.6 A, 160 m Ω

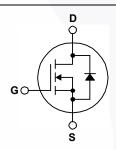
Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

Features

- 11.6 A, 150 V, $R_{DS(on)}$ = 160 m Ω (Max.) @ V_{GS} = 10 V, I_D = 5.8 A
- · Low Gate Charge (Typ. 23 nC)
- Low Crss (Typ. 30 pF)
- · 100% Avalanche Tested
- · 175°C Maximum Junction Temperature Rating





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Parameter	FQPF16N15	Unit
V _{DSS}	Drain-Source Voltage	150	V
I _D	Drain Current - Continuous (T _C = 25°C)	11.6	Α
	- Continuous (T _C = 100°C)	8.2	Α
I _{DM}	Drain Current - Pulsed (Note 1)	46.4	Α
V _{GSS}	Gate-Source Voltage	± 25	V
E _{AS}	Single Pulsed Avalanche Energy (Note 2)	230	mJ
I _{AR}	Avalanche Current (Note 1)	11.6	Α
E _{AR}	Repetitive Avalanche Energy (Note 1)	5.3	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)	6.0	V/ns
P _D	Power Dissipation (T _C = 25°C)	53	W
	- Derate Above 25°C	0.36	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range	-55 to +175	°C
T _L	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 seconds	300	°C

Thermal Characteristics

Symbol	Parameter FQPF16N15		Unit
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	2.78	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max. 62.5		C/VV

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FQPF16N15	FQPF16N15	TO-220F	Tube	N/A	N/A	50 units

Electrical Characteristics

T_C = 25°C unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Cha	aracteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	150			V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I _D = 250 μA, Referenced to 25°C		0.17		V/°C
I _{DSS}	Zana Cata Valtana Duain Courset	V _{DS} = 150 V, V _{GS} = 0 V			1	μА
	Zero Gate Voltage Drain Current	V _{DS} = 120 V, T _C = 150°C			10	μА
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 25 V, V _{DS} = 0 V			100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	V _{GS} = -25 V, V _{DS} = 0 V			-100	nA
On Cha	aracteristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.0		4.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = 10 V, I _D = 5.8 A		0.12	0.16	Ω
9 _{FS}	Forward Transconductance	V _{DS} = 40 V, I _D = 5.8 A		8.3		S
	ic Characteristics					
C _{iss}	Input Capacitance	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1.0 MHz		700	910	pF
C _{oss}	Output Capacitance			145	190	pF
C _{rss}	Reverse Transfer Capacitance			30	40	pF
Switchi	ing Characteristics					
t _{d(on)}	Turn-On Delay Time	V_{DD} = 75 V, I_{D} = 16.4 A, R_{G} = 25 Ω		11	30	ns
t _r	Turn-On Rise Time			115	240	ns
t _{d(off)}	Turn-Off Delay Time		/	50	110	ns
t _f	Turn-Off Fall Time	(Note 4		80	170	ns

Drain-Source Diode Characteristics and Maximum Ratings

I _S	Maximum Continuous Drain-Source Diode Forward Current				11.6	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current				46.4	Α
V _{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0 V, I _S = 11.6 A			1.5	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0 V, I _S = 16.4 A,	-	85		ns
Q _{rr}	Reverse Recovery Charge	dI _F / dt = 100 A/μs		0.35		μС

 V_{GS} = 10 V

 $V_{DS} = 120 \text{ V}, I_{D} = 16.4 \text{ A},$

Notes

 Q_{gs}

 Q_{gd}

- 1. Repetitive rating: pulse-width limited by maximum junction temperature.
- 2. L = 2.85 mH, I $_{AS}$ = 11.6 A, V $_{DD}$ = 25 V, R $_{G}$ = 25 $\Omega,$ starting $\,$ T $_{J}$ = 25 $^{\circ}C.$
- 3. $I_{SD} \leq$ 11.6 A, di/dt \leq 300 A/ μ s, $V_{DD} \leq$ BV $_{DSS}$, starting T_J = 25°C.
- ${\bf 4.} \ {\bf Essentially\ independent\ of\ operating\ temperature}.$

Total Gate Charge

Gate-Source Charge

Gate-Drain Charge

30

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4.5

11

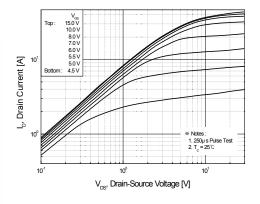
(Note 4)

nC

nC

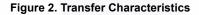
nC

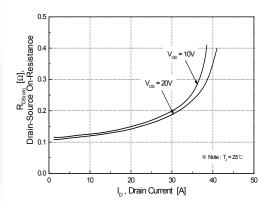
Typical Characteristics



10¹ 25°C ** Notes: 1.1/_{cm} 20V 2.25Uµs Prüse Test 1.0¹ 2 4 6 8 10 V_{cs}, Gate-Source Voltage [V]

Figure 1. On-Region Characteristics





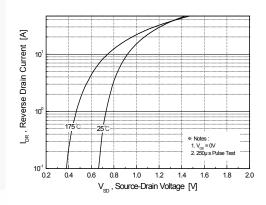
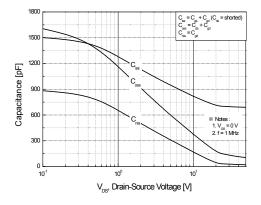


Figure 3. On-Resistance Variation vs.
Drain Current and Gate Voltage

Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature



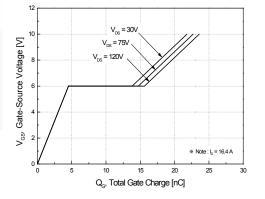


Figure 5. Capacitance Characteristics

Figure 6. Gate Charge Characteristics

Typical Characteristics (continued)

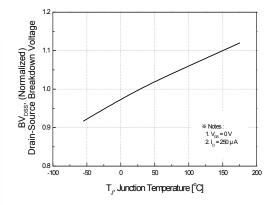
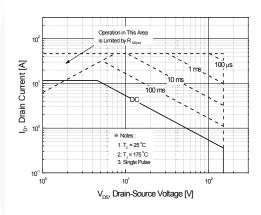


Figure 7. Breakdown Voltage Variation vs. Temperature

Figure 8. On-Resistance Variation vs. Temperature



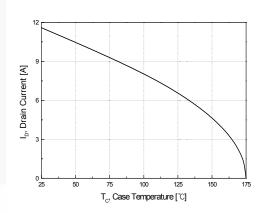


Figure 9. Maximum Safe Operating Area

Figure 10. Maximum Drain Current vs. Case Temperature

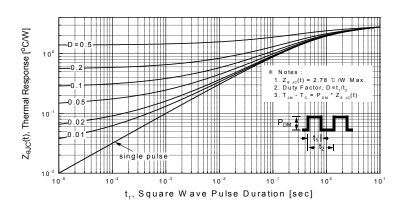


Figure 11. Transient Thermal Response Curve

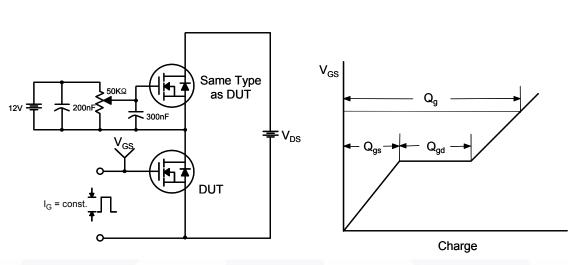


Figure 12. Gate Charge Test Circuit & Waveform

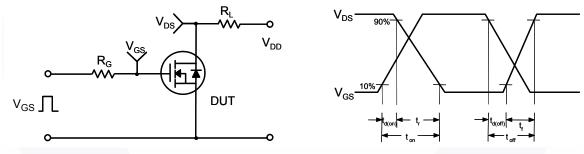


Figure 13. Resistive Switching Test Circuit & Waveforms

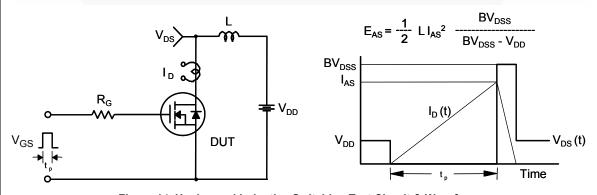
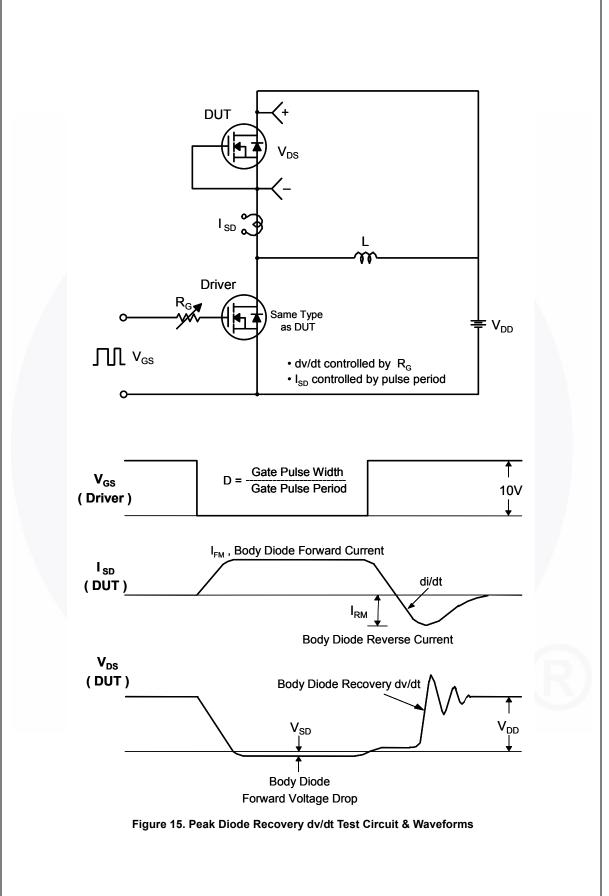


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms



Mechanical Dimensions

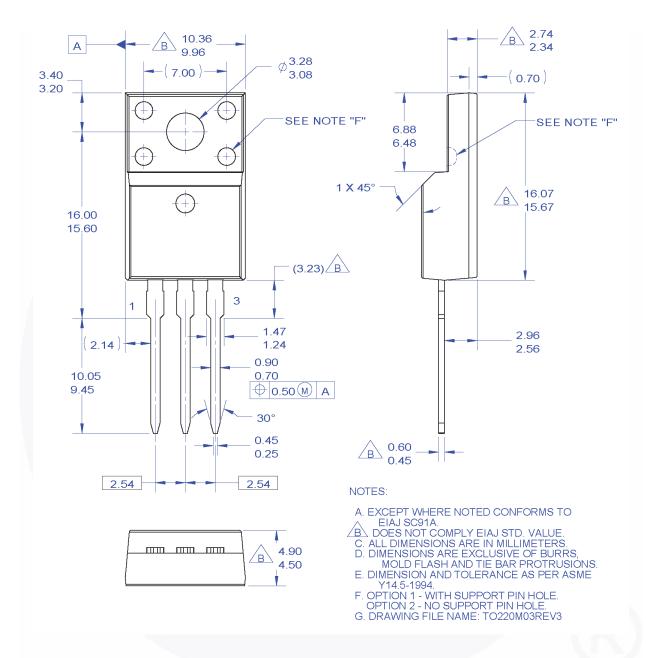


Figure 16. TO220, Molded, 3-Lead, Full Pack, EIAJ SC91, Straight Lead

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